

L Number	Hits	Search Text	DB	Time stamp
1	2	(semiconductor with gate) and (metal near oxide) and interface near (conductive near layer) and (gate near oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/30 19:30
8	4	"5858844"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/30 19:30

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